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With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

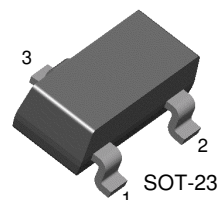
Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



KST4126

General Purpose Transistor



1. Base 2. Emitter 3. Collector

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

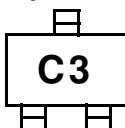
Symbol	Parameter	Value	Units
V_{CBO}	Collector-Base Voltage	-25	V
V_{CEO}	Collector-Emitter Voltage	-25	V
V_{EBO}	Emitter-Base Voltage	-4	V
I_C	Collector Current	-200	mA
P_C	Collector Power Dissipation	350	mW
T_{STG}	Storage Temperature	150	$^\circ\text{C}$
$R_{TH(j-a)}$	Thermal Resistance junction to Ambient	357	$^\circ\text{C/W}$

Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_C = -10\mu\text{A}, I_E = 0$	-25		V
BV_{CEO}	* Collector-Emitter Breakdown Voltage	$I_C = -1\text{mA}, I_E = 0$	-25		V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E = -10\mu\text{A}, I_C = 0$	-4		V
I_{CBO}	Collector Cut-off Current	$V_{CB} = -20\text{V}, I_E = 0$		-50	nA
I_{EBO}	Emitter Cut-off Current	$V_{BE} = -3\text{V}, I_C = 0$		-50	nA
h_{FE}	* DC Current Gain	$V_{CE} = -1\text{V}, I_C = -2\text{mA}$ $V_{CE} = -1\text{V}, I_C = -50\text{mA}$	120 60	360	
$V_{CE(sat)}$	* Collector-Emitter Saturation Voltage	$I_C = -50\text{mA}, I_B = -5\text{mA}$		-0.4	V
$V_{BE(sat)}$	* Base-Emitter Saturation Voltage	$I_C = -50\text{mA}, I_B = -5\text{mA}$		-0.95	V
f_T	Current Gain Bandwidth Product	$V_{CE} = -20\text{V}, I_C = -10\text{mA}, f = 100\text{MHz}$	250		MHz
C_{ib}	Input Capacitance	$V_{BE} = -0.5\text{V}, I_C = 0, f = 1\text{MHz}$		10	pF
C_{ob}	Output Capacitance	$V_{CB} = -5\text{V}, I_E = 0, f = 1\text{MHz}$		4.5	pF
NF	Noise Figure	$V_{CE} = -5\text{V}, I_C = -100\mu\text{A}, R_S = 1\text{K}\Omega$ Noise Bandwidth=10Hz to 15.7KHz		4	dB

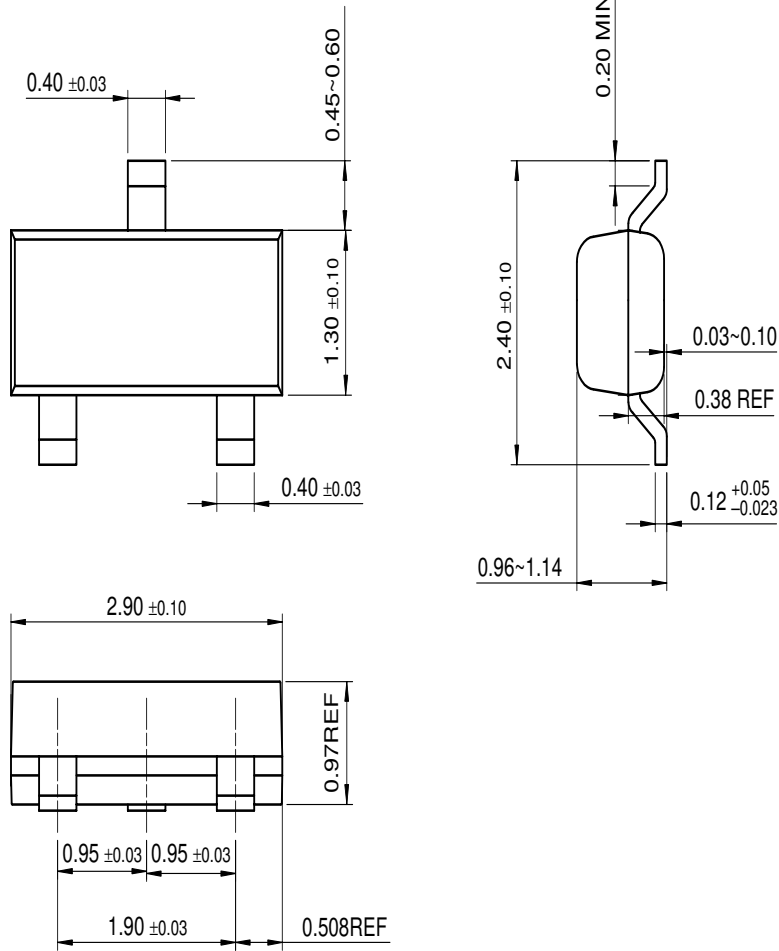
* Pulse Test: $PW \leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

Marking



Package Dimensions

SOT-23



Dimensions in Millimeters

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Datasheet Identification	Product Status	Definition
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